

10000TP8G10

- Pulse Amplifier
- M1-M5
- 10,000 Watts
- 8GHz-10GHz

Features

The Model 10000TP8G10 is a self contained, forced air cooled, broadband traveling wave tube (TWT) microwave amplifier designed for pulse applications at low to moderate duty factors where instantaneous bandwidth and high gain are required. A reliable TWT subsystem provides a conservative 10,000 watts minimum peak RF pulse power at the amplifier output connector. Stated power specifications are at the fundamental frequency.

The amplifier's front panel digital display shows forward and reflected average power output or forward and reflected peak power, plus extensive system status information accessed through a series of menus via soft keys. Status indicators include power on, warm-up, standby, operate, faults, excess average or peak reflected power warning and remote. Standard features include a built-in IEEE-488 (GPIB) interface, OdBm input, TTL Gating, VSWR protection, gain control, RF output sample ports, auto sleep, plus monitoring of TWT helix current, cathode voltage, collector voltage, heater current, heater voltage, baseplate temperature and cabinet temperature. Modular design of the power supply and RF

components allow for easy access and repair. Use of switching mode power supplies results in significant weight reduction.

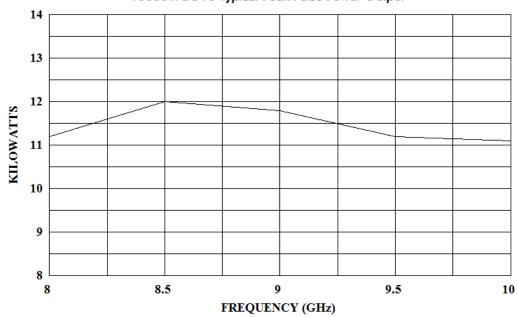
The rated power is developed by efficiently power combining the outputs from two 6000 watts (nominal) microwave tubes that are factory matched in gain and phase to offer moderate harmonic levels without added filters.

Housed in a stylish contemporary cabinet, the amplifier provides readily available pulsed RF power for a variety of applications in Test and Measurement, (including EMC RF pulse susceptibility testing), Industrial and University Research and Development, and Service applications. AR also offers a broad range of amplifiers for CW (Continuous Wave) applications.

The export classification for this equipment is 3A999.d. These commodities, technology or software are controlled for export in accordance with the U.S. Export Administration Regulations. Diversion contrary to U.S. law is prohibited.

See Model Configurations for alternative packaging, and special features.

10000TP8G10 Typical Peak Pulse Power Output



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Specifications

POWER (Fundamental), Peak Pulse, @ Output: Nominal, 11000 watts; Minimum, 10000 watts

FLATNESS: ±6 dB maximum

FREQUENCY RESPONSE: 8-10 GHz

INPUT FOR RATED OUTPUT: 1.0 milliwatt maximum

GAIN (at maximum setting): 70 dB minimum

GAIN ADJUSTMENT (continuous range): 35 dB mini-

mum

INPUT IMPEDANCE: 50 ohms, VSWR 2.5:1 maximum

OUTPUT IMPEDANCE: 50 ohms, VSWR 2.5:1 typical

MISMATCH TOLERANCE: Output pulse width foldback protection at peak reflected power exceeding 5000 watts. Will operate without damage or oscillation with any magnitude and phase of source and load impedance. May oscillate with unshielded open due to coupling to input. Should not be tested with connector off.

PULSE CAPABILITY:

Pulse Width 0.07 – 40 microseconds.
Pulse Rate (PRF) 100 kHz maximum
Duty Cycle 4% maximum.

RF Rise and Fall 30 ns max (10% to 90%).

Delay 300 ns maximum from pulse

input to RF 90%

Pulse Width Distortion ±30 ns maximum (50% points

of output pulse width compared to 50% points of input pulse

width)

Pulse Off Isolation 80 dB minimum, 90 dB typical Pulse Input TTL level, 50 ohm nominal

TTL level, 50 ohm nominal termination

Model Configurations

E Package Alternatives. May select an alternative from the following [E1C or (E1C and E2S) and/or E3H]:

E1C Cabinet: Without outer enclosure for rack mounting, size (W x H x D) 49 x 45 (10U) x 74 cm, 19 x 17.5 (10U) x 29 in., Subtract approximately 16 kg, 35 lbs, for removal of outer enclosure

E2S Slides: slides installed, add approximately 2 kg, 5 lbs.

E3H Handles: Front pull handles installed.

NOISE POWER DENSITY:

(pulse on) Minus 65 dBm/Hz maximum; Minus 69 dBm/Hz typical

(pulse off) Minus 140 dBm/Hz (typical)

PRIMARY POWER: 190-260 VAC, 50/60 Hz single

phase, 2.5 KVA maximum

CONNECTORS:

RF input: Type N female, rear panel
RF output: Type WR90 waveguide flange, rear
panel

RF output forward and reflected sample ports:

Type N female, rear panel
Pulse input: Type BNC female, rear panel
GPIB: IEEE-488 female, rear panel
Interlock: DB-15 female, rear panel

COOLING: Forced air (self contained fans), air entry

and exit in rear.

SIZE (W x H x D): 50.3 x 49 x 74 cm, 19.8 x 19 x 29 in

WEIGHT (approximate): 107 kg, 235 lbs **EXPORT CLASSIFICATION:** 3A999.d

	Features
Model Number	E
10000TP8G10	Base model
M1	E1C
M2	E3H
M3	E1C & E3H
M4	E1C & E2S
M5	E1C & E2S & E3H

Model number example: Model

10000TP8G10M2 would have option E3H front